



Low-Power Cellular Upconverter-Driver

MAX2307

General Description

The MAX2307 is an integrated RF upconverter-driver optimized for the Japanese cellular frequency band. It can also be used for applications in the US cellular and ISM bands. Its low current consumption (15mA at -15dBm output) extends the average talk time.

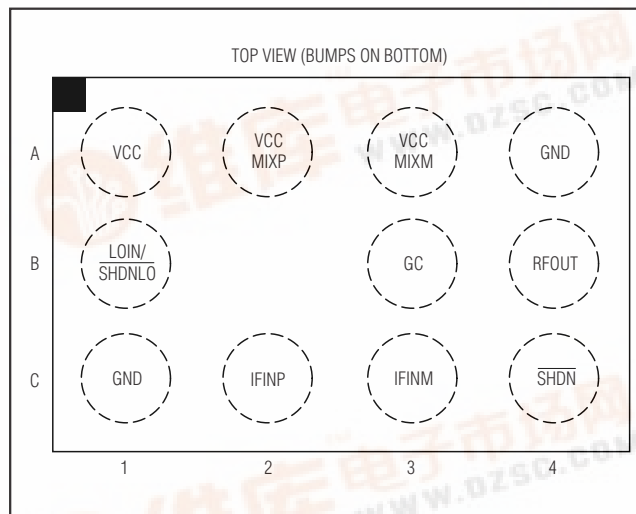
The image rejection is done using only two external inductors at the upconverter output because the image frequency in Japanese cellular phones is typically 330MHz away. This realizes the image rejection with no current consumption penalty and only two inexpensive off-chip components, saving cost and valuable board space.

The MAX2307 has a separate shutdown control for the LO buffer to minimize VCO pulling. It comes in an ultra-small 3x4 ultra-chip scale package (UCSP).

Applications

Cellular Handsets
cdmaOne™ Handsets
ISM Band

Pin Configuration



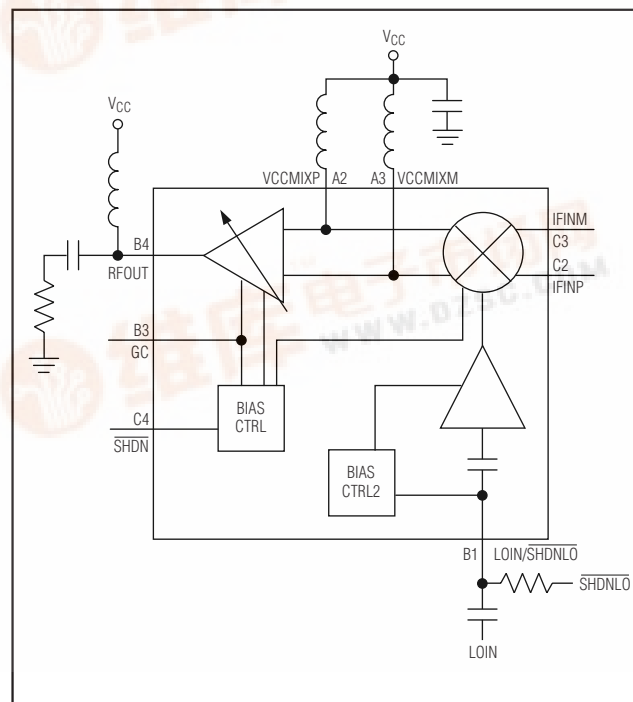
Features

- ◆ Ultra-Small Implementation Size
- ◆ Low Off-Chip Component Count
- ◆ 15mA at -15dBm P_{OUT}
- ◆ 34mA at +6.5dBm P_{OUT} and -53dBc ACPR
- ◆ <1μA Shutdown Mode
- ◆ Separate Shutdown for LO Buffer
- ◆ No External Logic Interface Circuitry Required

Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX2307EBC	-40°C to +85°C	3x4 UCSP

Block Diagram



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ABSOLUTE MAXIMUM RATINGS

V_{CC}, RFOUT to GND-0.3V to +5.5V
 SHDN to GND.....-0.3V to (V_{CC} + 0.3V)
 RF, IF Input Power0dBm
 Continuous Power Dissipation (T_A = +70°C)
 3x4 UCSP (derate 80mW/°C above +70°C)628mW

Operating Temperature Range-40°C to +85°C
 Junction Temperature+150°C
 Storage Temperature Range-65°C to +160°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

(V_{CC} = +2.8V to +4.2V, T_A = -40°C to +85°C, no RF/IF signals applied, V_{SHDN} = V_{SHDNLO} = +1.8V. Typical values are at V_{CC} = +3.0V, T_A = +25°C, unless otherwise noted).

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	V _{CC}		2.8		4.2	V
Shutdown Supply Current	I _{CC}	SHDN = SHDNLO = 0.6V		0.1	20	μA
Standby Supply Current	I _{CC}	SHDN = 0.6V, SHDNLO = 1.8V		2.5	4	mA
Supply Current (Note 1)	I _{CC}	V _{GC} = 2.2V, P _{OUT} = +6.5dBm		33.5	42	mA
		V _{GC} = 2.2V, P _{OUT} = +2dBm		29.5	38	
		V _{GC} = 0.5V		14	20	
Supply Current with No RF Drive	I _{CC}	V _{GC} = 2.2V		28	36.5	mA
Gain Control Voltage	V _{GC}		0		3.0	V
SHDN, SHDNLO Logic High			1.8			V
SHDN, SHDNLO Logic Low			0		0.6	V
SHDN, SHDNLO Logic Current High					1	μA
SHDN, SHDNLO Logic Current Low			1			μA

Low-Power Cellular Upconverter-Driver

AC ELECTRICAL CHARACTERISTICS

(MAX2307 Evaluation Kit, $V_{CC} = +2.8V$ to $+4.2V$, $T_A = -40^{\circ}C$ to $+85^{\circ}C$, $f_{RF} = 887MHz$ to $925MHz$, $f_{LO} = 722MHz$ to $760MHz$, $f_{IF} = 165MHz$, $P_{IFIN} = -20dBm$, $P_{LOIN} = -15dBm$, $V_{SHDN} = V_{SHDNLO} = +1.8V$, 50Ω system. Typical values are at $V_{CC} = 3.0V$, $V_{SHDN} = V_{SHDNLO} = 1.8V$, $f_{RF} = 906MHz$, $T_A = +25^{\circ}C$, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
RF Frequency Range (Note 2)			887		925	MHz
Power Gain	G	$V_{GC} = 2.2V$, $V_{CC} = 3.0V$, $T_A = +25^{\circ}C$	21.5	24.5	27.5	dB
		$V_{GC} = 2.2V$, $V_{CC} = 2.8V$ to $4.2V$, $T_A = T_{MIN}$ to T_{MAX}	17	24.5	32.5	
Output Power	P_{OUT}	$V_{GC} = 2.2V$, $ACPR \leq -53dBc$, $ALT \leq -65dBc$	4.5	6.5		dBm
LO Input Power Level			-15	-12	-5	dBm
Gain Control Range		$V_{GC} = 0.5V$ to $2.2V$, $P_{IFIN} = -30dBm$	18	23		dB
Gain Control Slope (Note 3)		$V_{GC} = 0.5V$ to $2.2V$, $P_{IFIN} = -30dBm$		32	36	dB/V
Adjacent Channel Power Ratio	ACPR1	Offset = $\pm 885kHz$ in 30kHz BW			-53	dBc
Alternate Channel Power Ratio	ACPR2	Offset = $\pm 1.98MHz$ in 30kHz BW			-65	dBc
RX Band Noise Power (Note 4)	P_{NOISE}	$P_{OUT} = 6.5dBm$		-134	-131	dBm/Hz
		$P_{IFIN} = -50dBm$, $V_{GC} = 0.5V$		-147		
LO Leakage		P_{OUT} from $+6.5dBm$ to $-8dBm$		-43	-30	dBc
Image Leakage (Note 1)		P_{OUT} from $6.5dBm$ to $-8dBm$, $f_{RF} = 887MHz$ to $925MHz$, $f_{IMAGE} = 557MHz$ to $595MHz$		-40	-25	dBc

Note 1: Minimum and maximum limits are guaranteed by design and characterization.

Note 2: See *Typical Operating Characteristics* for operation outside this frequency range.

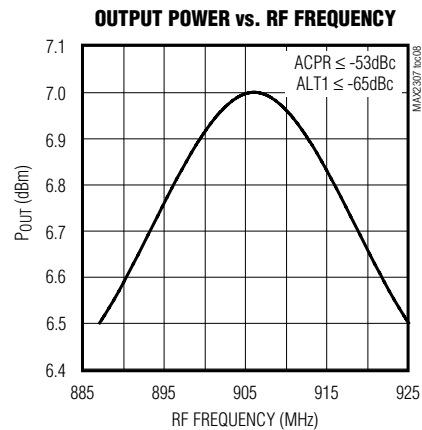
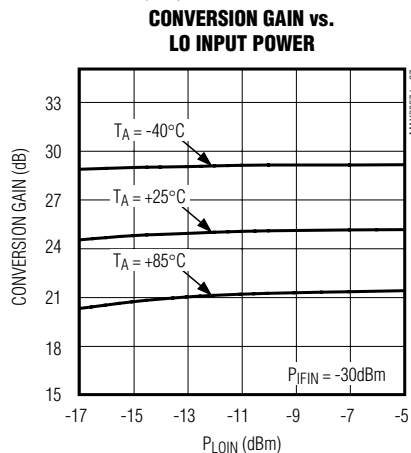
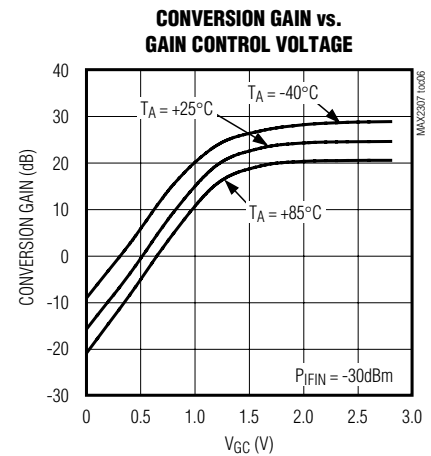
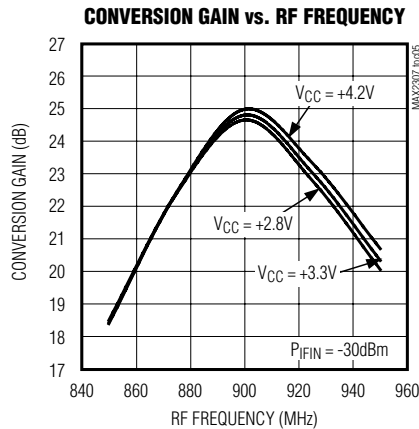
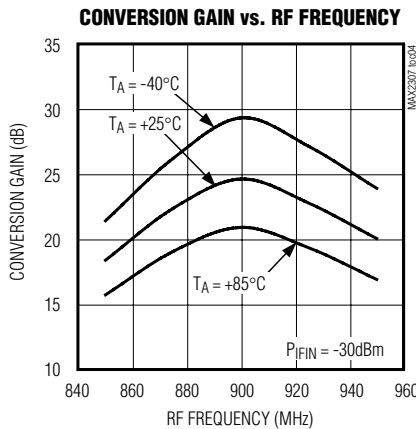
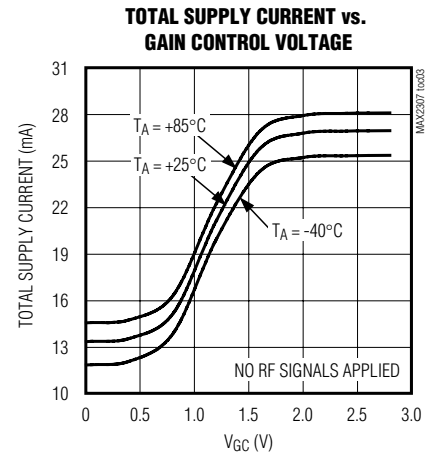
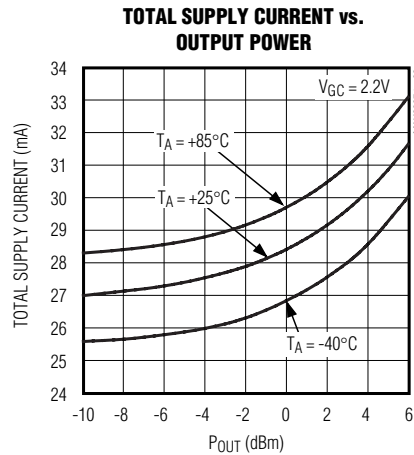
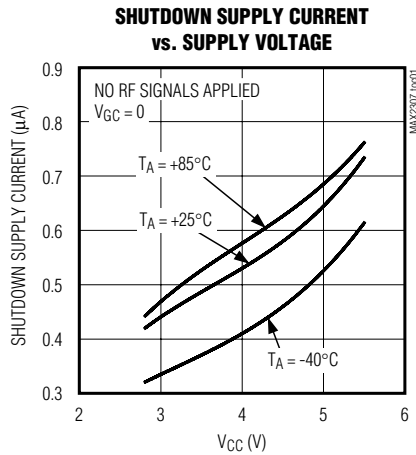
Note 3: Slope measured with $V_{GC} = +0.5V$ and $V_{GC} = +0.8V$.

Note 4: $f_{RF} = 925MHz$, noise measured at $870MHz$.

Low-Power Cellular Upconverter-Driver

Typical Operating Characteristics

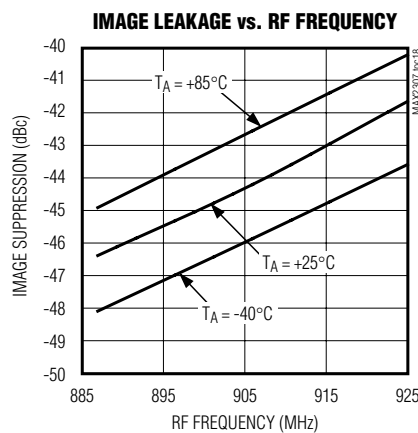
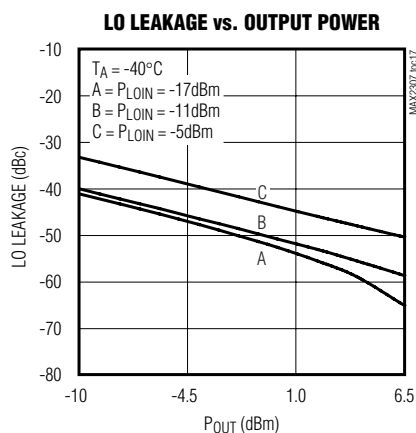
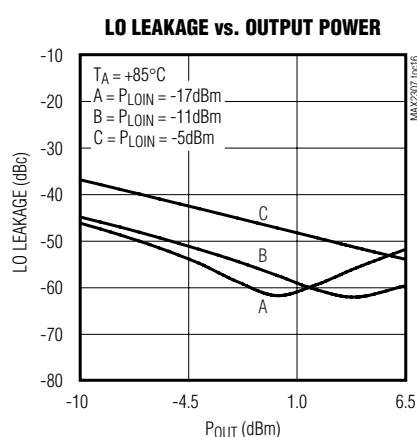
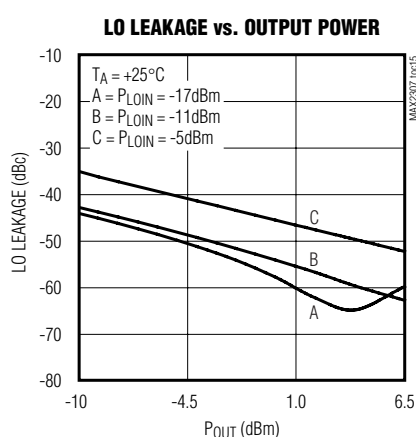
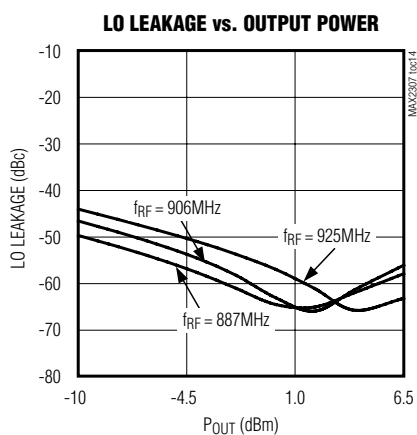
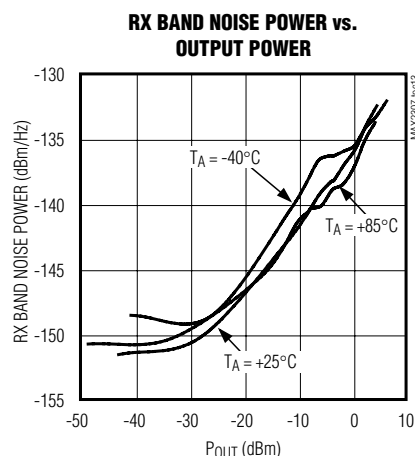
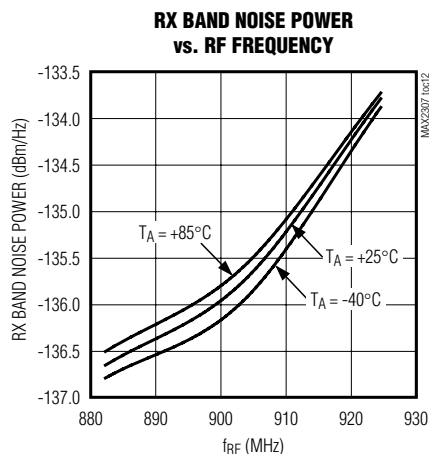
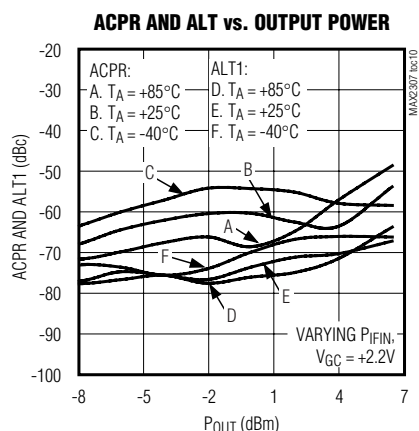
(MAX2307 Evaluation Kit, $V_{CC} = +2.8V$, $V_{GC} = 2.2V$, $V_{SHDN} = V_{SHDNLO} = V_{CC}$, $f_{RF} = 906MHz$, $f_{IF} = 165MHz$, $f_{LO} = 741MHz$, $T_A = +25^\circ C$, unless otherwise noted.)



Low-Power Cellular Upconverter-Driver

Typical Operating Characteristics (continued)

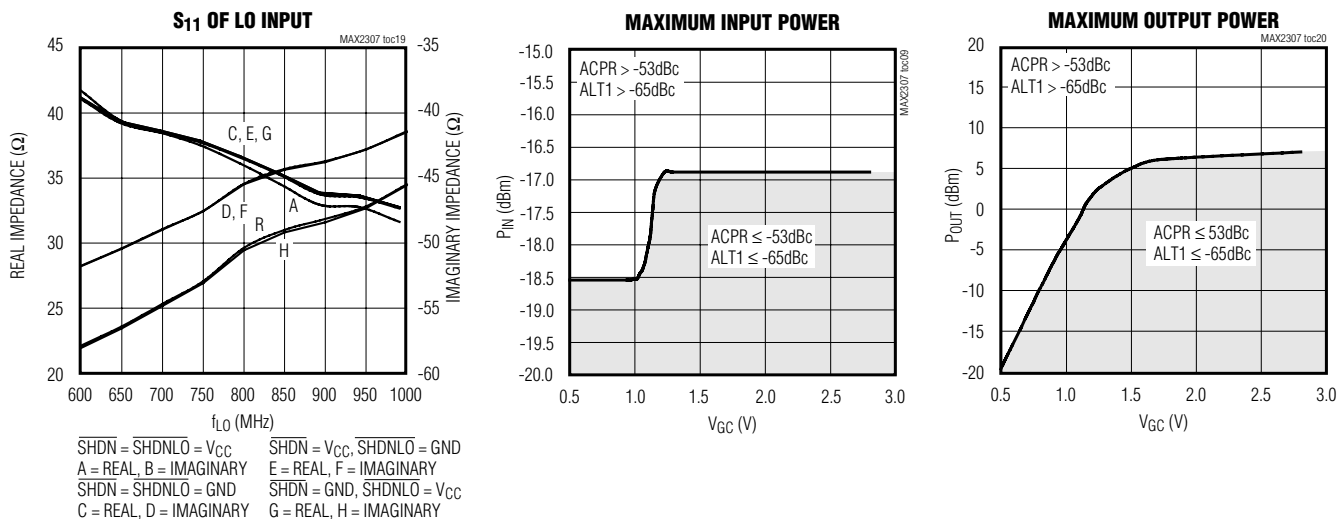
(MAX2307 Evaluation Kit, $V_{CC} = +2.8V$, $V_{GC} = 2.2V$, $V_{SHDN} = V_{SHDNLO} = V_{CC}$, $f_{RF} = 906MHz$, $f_{IF} = 165MHz$, $f_{LO} = 741MHz$, $T_A = +25^\circ C$, unless otherwise noted.)



Low-Power Cellular Upconverter-Driver

Typical Operating Characteristics (continued)

(MAX2307 Evaluation Kit, $V_{CC} = +2.8V$, $V_{GC} = 2.2V$, $V_{SHDN} = V_{SHDNLO} = V_{CC}$, $f_{RF} = 906MHz$, $f_{IF} = 165MHz$, $f_{LO} = 741MHz$, $T_A = +25^\circ C$, unless otherwise noted.)



Pin Description

PIN	NAME	FUNCTION
A1	VCC	Supply Pin. Bypass with 100pF and 0.01μF capacitors as close to the pin as possible.
A2, A3	VCCMIXP, VCCMIXM	Mixer Supply Pins. Require pullup inductors, which are used as part of the image rejection filter network. Supply to inductors should be locally bypassed with 100pF and 0.01μF capacitors.
B1	LOIN/ \overline{SHDNLO}	LO Input and LO Buffer Shutdown. Apply both LO input signal and LO buffer shutdown control to this pin. The LO path requires a DC-blocking capacitor. A logic high on \overline{SHDNLO} turns on the LO buffer, and a logic low turns off the LO buffer, independently of \overline{SHDN} . The shutdown control requires a 10k Ω isolation resistor in order not to load the LO signal.
B3	GC	Gain Control Pin. Apply a voltage between 0 to 3V to vary the gain of the IC.
B4	RFOUT	PA Driver Output. Requires an inductor pullup and a DC-blocking capacitor. These components are also the matching elements.
A4, C1	GND	GND Connection. Solder directly to the PCB ground plane, with three ground vias around the corner of the UCSP, as close to bump as possible. It is imperative that GND sees a low inductance to the system ground plane. See the MAX2307 EV Kit as an example.
C2, C3	IFINP, IFINM	Upconverter IF Inputs. AC-couple IF signals to these pins.
C4	\overline{SHDN}	Shutdown Control. HIGH turns on the device except the LO buffer, LOW turns off the device except the LO buffer.

MAX2307

Low-Power Cellular Upconverter-Driver

well as a low impedance to ground through the bypass capacitor.

Impedance-Matching Network Layout

The RFOUT matching network is very sensitive to layout-related parasitics. To minimize parasitic inductance, keep all traces short and place components as close as possible to the chip. To minimize parasitic capacitance, minimize the area of the plane.

Chip Information

TRANSISTOR COUNT: 693
PROCESS TECHNOLOGY: Silicon Bipolar

Package Information

